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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/710,844	08/06/2004	Cheng Chang Kuo	13137-US-PA	4843	
JIANQ CHYUN INTELLECTUAL PROPERTY OFFICE 7 FLOOR-1, NO. 100			EXAMINER		
			ERDEM, FAZLI		
ROOSEVELT ROAD, SECTION 2 TAIPEI, 100 TAIWAN		ART UNIT	PAPER NUMBER		
		·	2826		
·			NOTIFICATION DATE	DELIVERY MODE	
			08/01/2007	ELECTRONIC	

## Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Notice of the Office communication was sent electronically on above-indicated "Notification Date" to the following e-mail address(es):

USA@JCIPGROUP.COM.TW

ì		Application No.	Applicant(s)					
Office Action Summary		10/710,844	KUO, CHENG CHANG					
		Examiner	Art Unit					
		Fazli Erdem	2826					
	The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply							
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.  - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).								
Status			•					
1)🛛	Responsive to communication(s) filed on 26 A	oril 2007.						
2a) <u></u> □	This action is FINAL. 2b) This action is non-final.							
3)	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Dispositi	on of Claims							
<b>4</b> )⊠	Claim(s) <u>1-4</u> is/are pending in the application.			•				
<u>-</u>	4a) Of the above claim(s) is/are withdrawn from consideration.							
_	5) Claim(s) is/are allowed.							
	S) Claim(s) 1-4 is/are rejected.							
7)	Claim(s) is/are objected to.							
8) 🗀	Claim(s) are subject to restriction and/or	r election requirement.						
Applicati	on Papers							
9)	The specification is objected to by the Examine	r.						
	The drawing(s) filed on is/are: a)☐ acc		Examiner.					
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).								
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).								
11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.								
Priority u	ınder 35 U.S.C. § 119			•				
12)  Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a)  All b)  Some * c) None of:								
	1. Certified copies of the priority documents have been received.							
	2. Certified copies of the priority documents have been received in Application No							
3. Copies of the certified copies of the priority documents have been received in this National Stage								
application from the International Bureau (PCT Rule 17.2(a)).								
* See the attached detailed Office action for a list of the certified copies not received.								
Assault								
Attachment	e of References Cited (PTO-892)	1) Interview Summer:	(PT∩-413\					
2) Notic	e of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail Da	4) Interview Summary (PTO-413) Paper No(s)/Mail Date					
•	nation Disclosure Statement(s) (PTO/SB/08) r No(s)/Mail Date	5) Notice of Informal Pa	atent Application					

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## **DETAILED ACTION**

## Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 1-4 rejected under 35 U.S.C. 103(a) as being unpatentable over Zhang (6,855,954) in view of Lin (5,864,150)

Regarding Claims 1-4, Zhang discloses a thin film transistor and liquid crystal display having the thin film transistor where in Fig. 1C it is disclosed a gate 4 disposed on the substrate, a gate dielectric layer 6 disposed on the gate, a pattern semiconductor layer 8, a patterned, silicon dioxide or silicon oxide, insulating layers 10 and 11 and an ohmic layer (p or n type) 12 disposed on the silicon layer. Passivation layer 14 covers insulating layers 10 and 11. Zhang fails to disclose the required configuration where the central portion of the channel semiconductor layer is polysilicon and the side portions are amorphous. However, Lin discloses a hybrid polysilicon/amorphous silicon TFT and method of fabrication where layer 50 includes a polysilicon center channel portion and amorphous side portions as shown in Fig. 7 and claim 1. (Examiner considers the amorphous side portions of layer 50 in Fig. 7 of Lin to be "hot carrier restraint portion" since carriers act slower in the amorphous silicon layer as compared to the polycrystalline silion/polysilicon layer.)

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It would have been obvious to one of having ordinary skill in the art at the time the invention was made to include the required polysilicon center portion and the amorphous side portions for the channel region in Zhang as taught by Lin. in order to have a thin film transistor structure with increased reliability.

Regarding Claim 2, passivation layer is labeled as 14 in Zhang Fig. 1C

Regarding Claim 3, ohmic contact layer 12 of Zhang Fig. 1C is either n or p type

Regarding Claim 4, insulating layer 6, 10 and 11 are disclosed to be either silicon oxide or silicon nitride in Zhang as disclosed in column 1

## Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Fazli Erdem whose telephone number is (571) 272-1914. The examiner can normally be reached on M - F 8:00 - 5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Sue Purvis can be reached on (571) 272-1236. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

FE July 16, 2007

SUE A. PURVIS SUPERVISORY PATENT EXAM